

IFW



Docket No.: 61352-065

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	:	Customer Number: 20277
Hiroshi KANNO	:	Confirmation Number: Not yet assigned
Serial No.: 10/736,627	:	Group Art Unit: Not yet assigned
Filed: December 17, 2003	:	Examiner: Not yet assigned
For: TRANSMISSION LINE AND SEMICONDUCTOR INTEGRATED CIRCUIT DEVICE	:	

INFORMATION DISCLOSURE STATEMENT

Mail Stop IDS
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form PTO-1449. It is respectfully requested that the references be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

Each non-English language reference was first cited in a corresponding foreign application search report or office action and its relevance discussed therein. A copy of the

foreign search report or office action, together with an English language version thereof, is attached for the Examiner's information.

Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account 500417 and please credit any excess fees to such deposit account.

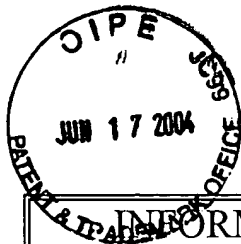
Respectfully submitted,

MCDERMOTT WILL & EMERY LLP



Michael E. Fogarty
Registration No. 36,139

600 13th Street, N.W.
Washington, DC 20005-3096
(202) 756-8000 MEF:gav
Facsimile: (202) 756-8087
Date: June 17, 2004



SHEET 1 OF 1

INFORMATION DISCLOSURE
CITATION IN AN
APPLICATION

(PTO-1449)

ATTY. DOCKET NO.
61352-065SERIAL NO.
10/736,627APPLICANT
Hiroshi KANNOFILING DATE
December 17, 2003GROUP
Not yet assigned

U.S. PATENT DOCUMENTS

EXAMINER'S INITIALS	CITE NO.	Document Number Number-Kind Code2 (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US			
		US			
		US			
		US			
		US			

FOREIGN PATENT DOCUMENTS

EXAMINER'S INITIALS	CITE NO.	Foreign Patent Document Country Codes -Number + -Kind Codes (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines Where Relevant Figures Appear	Translation	
						Yes	No
		JP 2002-171105 A	06/14/2002	SUMITOMO METAL ELECTRONICS DEVICES INC.		JAPAN (w/English Abstract)	
		JP 1-233812 A	09/19/1989	FUJITSU LTD.		JAPAN (w/English Abstract)	
		JP 9-275001 A	10/21/1997	TOSHIBA CORP.		JAPAN (w/English Abstract)	
		JP 2001-177305 A	06/29/2001	NEC CORP		JAPAN (w/English Abstract)	
		JP 11-261301 A	09/24/1999	NEC CORP		JAPAN (w/English Abstract)	
		JP 5-29834 A	02/05/1993	SAMSUNG ELECTRON CO LTD.		JAPAN (w/English Abstract)	
		JP 4-192902 A	07/13/1992	NEC YAMAGATA LTD.		JAPAN (w/English Abstract)	

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER'S INITIALS	CITE NO.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.
		Chen, T.H., et al. "One Watt Q-band Class A Pseudomorphic HEMT MMIC Amplifier." 1994, IEEE, MTT-S Digest, pp. 805-808.

EXAMINER

DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.